Unit: mm

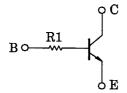
TOSHIBA Transistor Silicon Npn Epitaxial Type (PCT Process)

RN1610,RN1611

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in SM6 (super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2610, RN2611

Equivalent Circuit

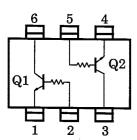


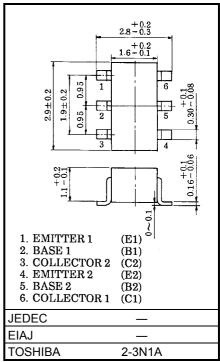
Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characterisstic	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	50	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	I _C	100	mA
Collector power dissipation	P _C *	300	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~150	°C

^{*} Total rating

Equivalent Circuit (Top View)



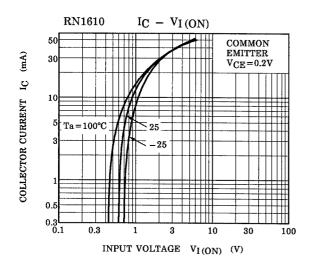


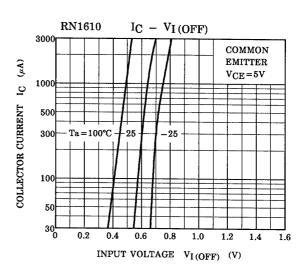
Weight: 0.015g

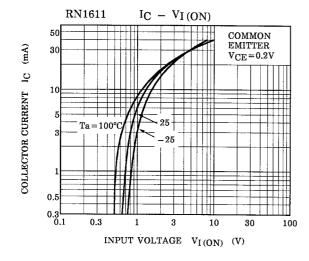
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

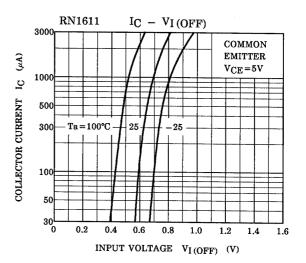
Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	_	V _{CB} = 50V, I _E = 0	_	_	100	nA
Emitter cut-off current		I _{EBO}	_	V _{EB} = 50V, I _C = 0	_	-	100	nA
DC current gain		h _{FE}	_	V _{CE} = 50V, I _C = 1mA	120	_	700	-
Collector-emitter saturation voltage		V _{CE} (sat)	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
Translation frequency		f _T	_	V _{CE} = 10V, I _C = 5mA	_	250	_	MHz
Collector output capacitance		C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1MHz	_	3	6	pF
Input resistor	RN1610	- R1	_	_	3.29	4.7	6.11	kΩ
	RN1611				7	10	13	

(Q1, Q2 Common)

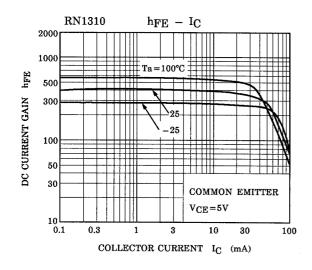


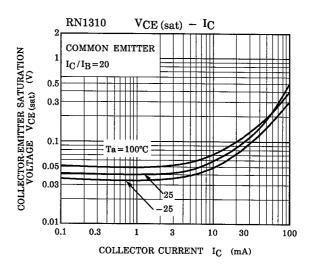


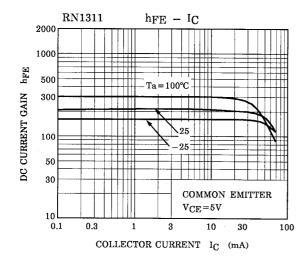


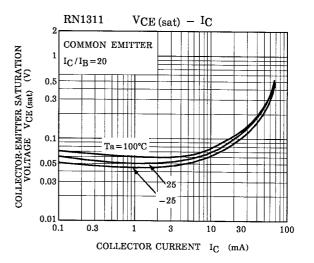


(Q1, Q2 Common)









Type Name	Marking	
RN1610	Type Name X K	
RN1611	Type Name X M	

2001-06-07

4

RESTRICTIONS ON PRODUCT USE

000707EAA

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